

## SANYO Semiconductors DATA SHEET

### LA75676M-

# Monolithic Linear IC For TV and VCR Products IF Signal Processor (VIF+SIF)

#### Overview

The LA75676M is a VIF/SIF IC that supports NTSC intercarrier reception and adopts a semi-adjustment-free design. It is provided in the MFP24S (300mil, 1.0mm lead pitch) package, which is appropriate for miniature 2-in-1 tuner products. In the VIF block, it adopts a design that uses AFT adjustment to obviate the need for VCO adjustment, and thus can simplify the adjustment steps required in end product manufacturing. It uses a PLL technique for FM detection. It features the 5V supply voltage appropriate for multimedia products. In addition, it achieves superb audio quality by incorporating a buzz canceller that suppresses Nyquist buzzing.

#### **Functions**

- VIF block: VIF amplifier, buzz canceller, PLL detector, IF AGC, RF AGC, AFT, and an equalizer amplifier
- SIF block: Limiter amplifier, PLL FM detector

#### **Specifications**

**Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		6	V
Circuit voltage	V13, V17		V <sub>CC</sub>	V
Circuit current	16		-3	mA
	I10		-10	mA
	124		-2	mA
Allowable power dissipation	Pd max	Ta ≤ 70°C * Mounted on a board	400	mW
Operating temperature	Topr		-20 to +70	°C
Storage temperature	Tstg		-55 to +150	°C

<sup>\*</sup> When mounted on a 114.3×76.1×1.6mm³, glass epoxy board.

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#### **LA75676M**

#### Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	Vcc		5	V
Operating supply voltage range	V <sub>CC</sub> op		4.5 to 5.5	V

#### **Electrical Characteristics** at Ta = 25 °C, $V_{CC} = 5V$ , fp = 45.75 MHz

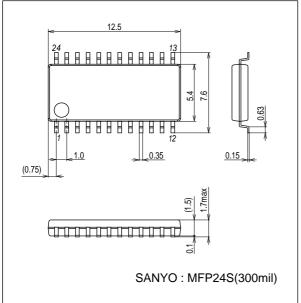
Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
[VIF Block]						
Circuit current	15		32	40	48	mA
Maximum RF AGC voltage	V14H		V <sub>CC</sub> -0.5	VCC		V
Minimum RF AGC voltage	V14L			0	0.5	V
Input sensitivity	Vi	S1 = OFF	32	38	44	dΒμV
AGC range	GR		58	63		dB
Maximum allowable input	Vi max		95	100		dΒμV
Video output voltage (no input)	V6		3.5	3.8	4.1	V
Sync signal tip voltage	V6tip		0.9	1.2	1.5	V
Video output level	Vo		1.7	2	2.3	Vp-p
Black noise threshold voltage	VBTH		0.5	0.8	1.1	V
Black noise clamp voltage	VBCL		1.6	1.9	2.2	V
Video signal-to-noise ratio	S/N		48	52		dB
C-S beating	IC-S		38	43		dB
Frequency characteristics	fc	6MHz	-3	-1.5		dB
Differential gain	DG			3	6.5	%
Differential phase	DP			3	5	°C
AFT voltage (no signal)	V13		2.0	2.5	3.0	V
Maximum AFT voltage	V13H		4.0	4.4	5.0	V
Minimum AFT voltage	V13L			0.18	1.0	V
AFT detection sensitivity	Sf		28	40	52	mV/kHz
VIF input resistance	Ri	45.75MHz		1.5		kΩ
VIF input capacitance	Ci	45.75MHz		3		pF
APC pull-in range (U)	fpu		1.3	2.0		MHz
APC pull-in range (L)	fpl			-2.0	-1.4	MHz
AFT tolerance frequency 1	dfa1		-150	0	+150	kHz
VCO 1 maximum range (U)	dfu		1.5	2.0		MHz
VCO 1 maximum range (L)	dfl			-2.0	-1.5	MHz
VCO control sensitivity	В		1.3	2.7	5.4	kHz/mV
[SIF BLOCK]	•					
Limiting sensitivity	VIi (lim)		39	45	51	dΒμV
FM detection output voltage*	V <sub>O</sub> (FM)	4.5MHz ±25kHz	400	520	660	mVrms
AMR	AMR		50	60		dB
Total harmonic distortion	THD			0.3	0.8	%
SIF signal-to-noise ratio	S/N (FM)		59	64		dB
4.5MHz output level	Vsout	SIF IN 80dBμV	87	94	101	dΒμV

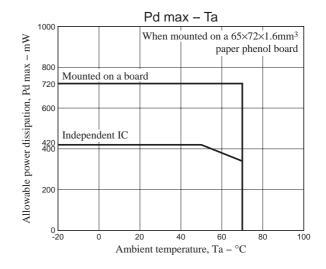
<sup>\*:</sup> If a wider FM detection output dynamic range is required, insert a resistor and capacitor in series between pin 23 and ground to adjust the level.

#### **Package Dimensions**

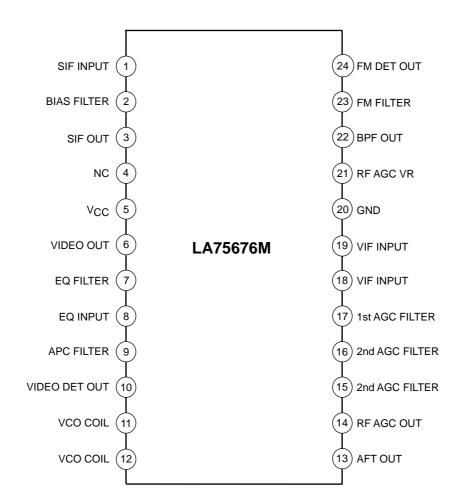
unit: mm (typ)



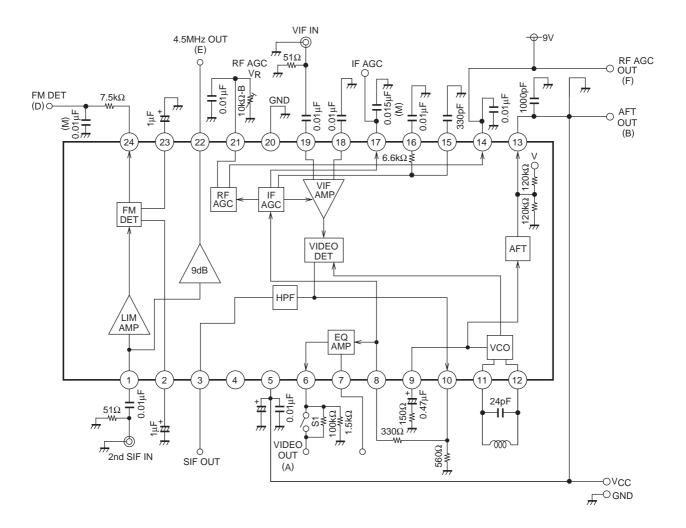




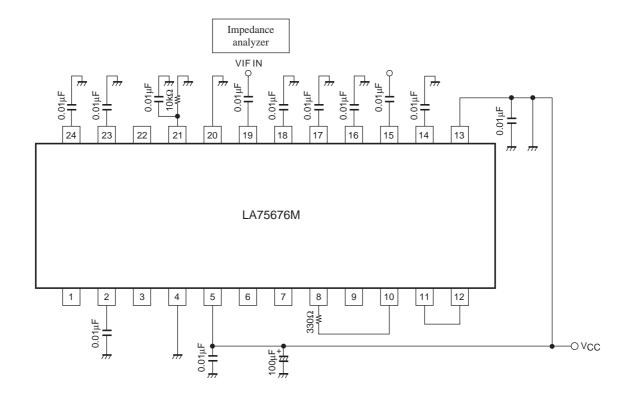
#### **Pin Assignment**



#### **Block Diagram and AC Characteristics Test Circuit**



#### **Test Circuit** (Input inpedance)



#### **Test Conditions**

- V1. Circuit current • • [15]
  - 1. Internal AGC
  - 2. Input a 45.75MHz, 10mVrms, CW signal to the VIF input pin.
  - 3. RF AGC Vr maximum
  - 4. Connect a current meter to V<sub>CC</sub> and measure the current flowing into the IC.

#### V2, V3. Maximum RF AGC voltage, minimum RF AGC voltage •••• [V9H, V9L]

- 1. Internal AGC
- 2. Input a 45.75MHz, 10mVrms, CW signal to the VIF input pin.
- 3. Vary the RF AGC Vr and, at the maximum resistance, measure the maximum RF AGC voltage. (F)
- 4. Vary the RF AGC Vr and, at the minimum resistance, measure the maximum RF AGC voltage. (F)

#### V4. Input sensitivity • • • • [Vi]

- 1. Internal AGC
- 2. fp = 45.75MHz, 400Hz 40% AM (VIF input)
- 3. Set S1 to the off position and pass the input through a  $100k\Omega$  resistor.
- 4. Measure the VIF input level such that the 400Hz detection output level at test point A becomes 0.64Vp-p.

#### V5. AGC range • • • • [GR]

- 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC input (pin 17).
- 2. With the same conditions as used for V4, measure the VIF input level such that the detection output level becomes 0.64Vp-p. • Vi1

3. 
$$GR = 20\log \frac{Vi1}{Vi} dB$$

#### V6. Maximum allowable input • • • • [Vi max]

- 1. Internal AGC
- 2. fp = 45.75MHz, 15kHz 78% AM (VIF input)
- 3. Measure the VIF input level such that the detection output level at test point A is  $\pm 1$ dB of the video output (Vo).

#### V7. Video output voltage (no input) • • • • [V6]

- 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC input (pin 17).
- 2. Measure the video output (A) DC voltage.

#### V8. Sync signal tip voltage • • • • [V6tip]

- 1. Internal AGC
- 2. Input a 45.75MHz, 10mVrms, CW signal to the VIF input pin.
- 3. Measure the video output (A) DC voltage.

#### V9. Video output level • • • • [VO]

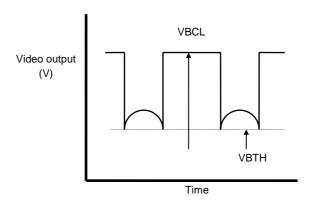
- 1. Internal AGC
- 2. fp = 45.75MHz, 15kHz 78% AM

$$Vi = 10mVrms$$
 (VIF input)

3. Measure the wave height of the detection output level at test point A. (Vp-p)

#### V10, V11. Black noise threshold and clamp voltages • • • • [VBTH, VBCL]

- 1. Apply a DC voltage to the external AGC IF input (pin 17) and vary that voltage.
- 2. fp = 45.75MHz, 400Hz, 40% AM, 10mVrms (VIF input)
- 3. Vary the IF AGC (pin 17) voltage so that the noise canceller operates. Measure VBTH and VBCL at test point A.



#### V12. Video signal-to-noise ratio • • • • [S/N]

- 1. Internal AGC
- 2. fp = 45.75MHz, CW, 10mVrms (VIF input)
- 3. Measure the noise voltage as an RMS level at test point A after passing through a 10kHz to 4MHz bandpass filter. This is the noise voltage (N).

4. S/N = 
$$20\log \frac{\text{Video component (Vp-p)}}{\text{Noise voltage (Vrms)}} = 20\log \frac{1.12\text{Vp-p}}{\text{Noise voltage}} = (dB)$$

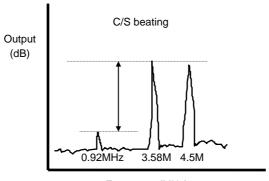
#### V13. C/S beating •••• [ICS]

- 1. Apply a DC voltage to the external AGC IF input (pin 17) and vary that voltage.
- 2. fp = 45.75MHz, CW; 10mVrms

fc = 42.17MHz, CW; 10mVrms - 10dB

fs = 41.25MHz, CW; 10mVrms - 10dB

- 3. Vary the IF AGC (pin 17) voltage to adjust the output level at test point A to be 1.3Vp-p.
- 4. Measure the difference in level between the 3.58MHz and the 0.92MHz components at test point A.



- V14. Frequency characteristics • • [fc]
  - 1. Apply a DC voltage to the external AGC IF input (pin 17) and vary that voltage.
  - 2. SG1: 45.75MHz, CW, 10mVrms
    - SG2: from 45.65MHz to 39.75MHz, CW, 2mVrms

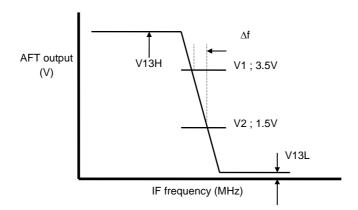
Add SG1 and SG2 using a T pad, adjust the signal generator levels to those listed above, and apply the result to VIF IN.

- 3. First, set the SG2 frequency to 45.65MHz.
  - Next, adjust the IF AGC voltage (pin 17) so that the output level at test point A becomes 0.5Vp-p. • V1
- 4. Set the SG2 frequency to 39.75MHz and measure the output level. • V2
- 5. Perform the following calculation.

$$fc = 20\log \frac{V2}{V1} (dB)$$

- V15, V16. Differential gain and differential phase • • [DG, DP]
  - 1. Internal AGC
  - 2. fp = 45.75MHz, APL 50%, 87.5% video signal, Vi = 10mVrms
  - 3. Measure DG and DP at test point A.
- V17. AFT voltage (no signal) • • V13
  - 1. Internal AGC
  - 2. Measure the DC voltage on the AFT output (B).
- V18, V19, V20. Maximum AFT voltage, minimum AFT voltage, AFT detection sensitivity • • [V13H, V13L, Sf]
  - 1. Internal AGC
  - 2. fp = 45.75MHz,  $\pm 1.5$ MHz sweep, 10mVrms (VIF input)
  - 3. Record the maximum voltage as V13H and the minimum voltage as V13L.
  - 4. Measure the frequency shift for the change in voltage at test point B from V1 to V2. • Δf

$$Sf = \frac{2000 \text{ (mV)}}{\Delta f \text{ (kHz)}} \text{ mV/kHz}$$



- V21, V22. VIF input resistance, input capacitance • • [Ri, Ci]
  - 1. Use an impedance analyzer to measure Ri and Ci in the input impedance test circuit.
- V23, V24. APC pull-in range • • [fpu, fpl]
  - 1. Internal AGC
  - 2. fp = 39MHz to 51MHz, CW : 10mVrms
  - 3. Vary the signal generator from fp = 45.75MHz towards higher frequencies until PLL lock is lost.

Note: PLL lock is lost at the point beating is output at test point A.

- 4. Lower the signal generator frequency until the PLL locks again. (f1)
- 5. Lower the signal generator frequency until PLL lock is lost.
- 6. Raise the signal generator frequency until the PLL locks again. (f2)
- 7. Perform the following calculations.

$$fpu = f1 - 45.75MHz$$
  
 $fpl = f2 - 45.75MHz$ 

- V25. AFT tolerance frequency 1 • • [ΔFa1]
  - 1. Internal AGC
  - 2. SG1: Vary this frequency from 43.75MHz to 47.75MHz, CW, 10mVrms
  - 3. Vary the SG1 frequency so that the AFT output (test point B) becomes 2.5V. Record the SG1 frequency at that point as f1.
  - 4. External AGC (Adjust V17.)
  - 5. Apply 5V to the IF AGC (pin 17), pick up the VCO oscillator frequency from ground or some other point, and measure that frequency. f2
  - 6. Perform the following calculation.

AFT tolerance frequency  $1 \Delta Fa1 = f2 - f1 (kHz)$ 

#### V26, V27. VCO maximum range (U, L) • • • • [dfu, dfl]

- 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC (pin 17).
- 2. Pick up the VCO oscillator frequency from the video output (A), ground, or some other point and adjust the VCO coil so that frequency becomes 45.75MHz.
- 3. Apply 1V to the APC pin (pin 9) and let fl be the frequency at that time.

Similarly, apply 5V and let fu be the frequency at that time.

$$dfu = fu - 45.75MHz$$
  
 $dfl = fl - 45.75MHz$ 

#### V28. VCO control sensitivity • • • • [β]

- 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC (pin 17).
- 2. Pick up the VCO oscillator frequency from the video output (A), ground, or some other point and adjust the VCO coil so that frequency becomes 45.75MHz.
- 3. Apply 3V to the APC pin (pin 9) and let f1 be the frequency at that time.

Similarly, apply 3.4V and let f2 be the frequency at that time.

$$\beta = \frac{f2 - f1}{400} \left( kHz/mV \right)$$

- S1. SIF limiting sensitivity • • [Vi (lim)]
  - 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC (pin 17).
  - 2. fs = 4.5MHz, fm = 400Hz,  $\Delta F = \pm 25$ kHz (SIF input)
  - 3. Set the SIF input level to 100mVrms and measure the value at test point D at that time. • V1
  - 4. Lower the SIF input level and measure the input level such that V1 is down by 3dB.
- S2, S4. FM detection output voltage, total harmonic distortion • • [VO(FM), THD]
  - 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC (pin 17).
  - 2. fs = 4.5MHz, fm = 400Hz,  $\Delta F = \pm 25$ kHz (SIF input, Vi = 100mVrms)
  - 3. Measure the FM detection output voltage and total harmonic distortion at test point D.

- S3. AM rejection ratio • • [AMR]
  - 1. External AGC. Apply the V<sub>CC</sub> voltage to the IF AGC (pin 17).
  - 2. fs = 4.5MHz, fm = 400Hz, AM = 30% (SIF input,  $Vi = 90dB\mu V$ )
  - 3. Measure the output voltage at test point D. • VAM

4. AMR = 
$$20\log \frac{V_O(DET)}{VAM} dB$$

- S5. SIF signal-to-noise ratio • • [S/N]
  - 1. External AGC (V17 =  $V_{CC}$ )
  - 2. fs = 4.5MHz, no modulation, Vi = 100mVrms
  - 3. Measure the output voltage at test point D. • • Vn

$$4.~S/N = 20log \frac{V_O(DET)}{Vn}~dB$$

- S6. 4.5MHz output level • • [S/N]
  - 1. External AGC (V17 =  $V_{CC}$ )
  - 2. fs = 4.5MHz, no modulation, Vi = 10mVrms
  - 3. Measure the output voltage at test point E. • • Vsout
- Note 1. Unless specified otherwise, when measuring VIF, apply the V<sub>CC</sub> voltage to the AGC and adjust the VCO coil so that it oscillates at 45.75MHz.
- Note 2. Unless specified otherwise, switch SW1 must be in the on position.

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